NSN 5961-01-102-8202

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View Online at https://aerobasegroup.com/nsn/5961-01-102-8202 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.295 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-59 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and radiation hardened **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator: Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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